

PATENT ASSIGNMENT COVER SHEET

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 Stylesheet Version v1.2

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SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT
CONVEYING PARTY DATA	
Name	Execution Date
SERGEY SOFER	12/06/2012
MICHAEL PRIEL	12/06/2012
NOAM SIVAN	12/06/2012
RECEIVING PARTY DATA	
Name:	FREESCALE SEMICONDUCTOR, INC.
Street Address:	6501 WILLIAM CANNON DRIVE WEST
City:	AUSTIN
State/Country:	TEXAS
Postal Code:	78735
PROPERTY NUMBERS Total: 1	
Property Type	Number
Application Number:	14655150
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ATTORNEY DOCKET NUMBER:	NS30300EC
NAME OF SUBMITTER:	ISABELLE BARBE
SIGNATURE:	/Isabelle BARBE/
DATE SIGNED:	06/24/2015
Total Attachments: 4	
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ASSIGNMENT AND AGREEMENT

For good and valuable consideration, the receipt of which is hereby acknowledged, we, **SOFER, Sergey, RISHON LEZION, ISRAEL, PRIEL, Michael, NETANYA, ISRAEL and SIVAN, Noam, GANEY TIKVA, ISRAEL** have sold, assigned and transferred, and do hereby sell, assign and transfer, unto **FREESCALE SEMICONDUCTOR, INC.**, a corporation of the State of Delaware, having its principal office in Austin, Texas, United States of America, and its successors, assigns, and legal representatives, the entire right, title and interest for the United States of America, in and to certain inventions relating to improvements in **METHOD AND CONTROL DEVICE FOR RECOVERING NBTI/PBTI RELATED PARAMETER DEGRADATION IN MOSFET DEVICES** (Docket No. NS30300EC), described, illustrated and claimed in an application for Letters Patent of the United States of America executed by us on the dates indicated by our signatures below, together with the entire right, title and interest in and to the application, and in and to Letters Patent which may be issued upon the application, and upon any division, extension, continuation or reissue thereof.

We hereby also sell, assign and transfer unto **FREESCALE SEMICONDUCTOR, INC.**, the entire right, title and interest in and to the invention and in and to applications for Letters Patent therefor in all countries foreign to the United States of America, including all rights under any and all international conventions and treaties in respect of the invention and the applications for Letters Patent in foreign countries, and we further authorize **FREESCALE SEMICONDUCTOR, INC.** to apply for Letters Patent in foreign countries directly in its own name, and to claim priority of the filing date of the application for Letters Patent of the United States of America under the provisions of any and all international conventions and treaties.

We hereby authorize and request the Commissioner of Patents of the United States of America to issue Letters Patent upon the aforesaid application, division, extension, continuation or reissue, to **FREESCALE SEMICONDUCTOR, INC.** for the sole use and benefit of **FREESCALE SEMICONDUCTOR, INC.** its successors, assigns and legal representatives; to the full end of the term for which Letters Patent may be granted, the same as they would have been held and enjoyed by me had this assignment not been made, and we hereby authorize and request the equivalent authorities in foreign countries to issue the patents of their respective countries to **FREESCALE SEMICONDUCTOR, INC.**

We agree that, when requested, we will, without charge to **FREESCALE SEMICONDUCTOR, INC.** but at its expense, sign all papers, take all rightful oaths, and do all acts which may be necessary, desirable or convenient for securing and maintaining patents for the inventions in any and all countries and for vesting title thereto in **FREESCALE SEMICONDUCTOR, INC.** its successors, assigns and legal representatives or nominees.

We covenant with FREESCALE SEMICONDUCTOR, INC., its successors, assigns and legal representatives, that the interest and property hereby conveyed is free from all prior assignment, grant, mortgage, license or other encumbrance.



SOFER, Sergey

DATE: Dec 6, 2012_____

First Witness



SIGNATURE OF WITNESS

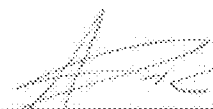
DATE: Dec 6, 2012_____

(Month-Day-Year)

Valery Neiman

PRINTED NAME OF WITNESS

Second Witness



SIGNATURE OF WITNESS

DATE: Dec 6, 2012_____

(Month-Day-Year)

Eyal Melamed Cohen

PRINTED NAME OF WITNESS

PRIEL, Michael

DATE: Dec 6, 2012

First Witness

SIGNATURE OF WITNESS

DATE: Dec 6, 2012

(Month-Day-Year)

Valery Neiman

PRINTED NAME OF WITNESS

Second Witness

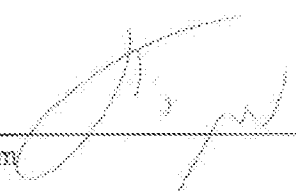
SIGNATURE OF WITNESS

DATE: Dec 6, 2012

(Month-Day-Year)

Eyal Melamed Cohen

PRINTED NAME OF WITNESS


SIVAN, Noam

DATE: Dec 6, 2012

First Witness


SIGNATURE OF WITNESS

DATE: Dec 6, 2012

(Month-Day-Year)

Valery Neiman

PRINTED NAME OF WITNESS

Second Witness


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Eyal Melamed Cohen

PRINTED NAME OF WITNESS

NS30300EC

4